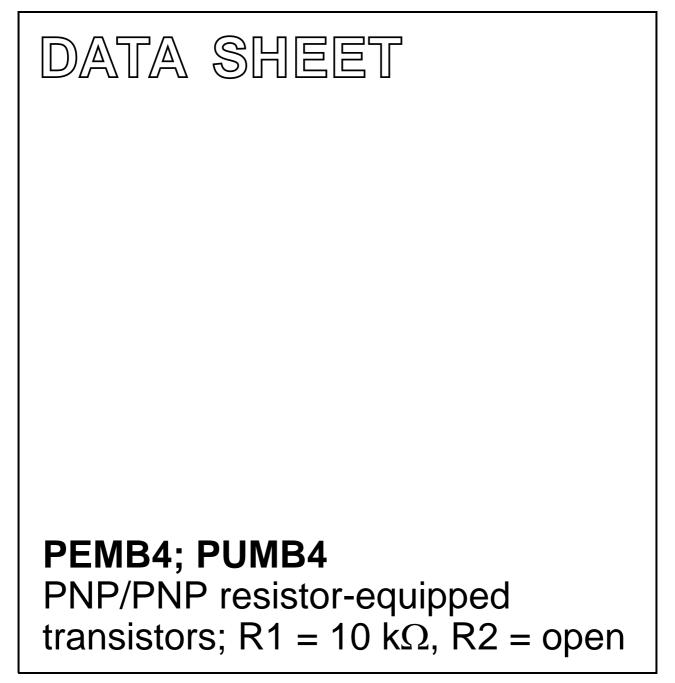
DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 2001 Sep 14 2003 Oct 15



## PEMB4; PUMB4

### FEATURES

- · Built-in bias resistors
- Simplified circuit design
- Reduction of component count
- Reduced pick and place costs.

### APPLICATIONS

- Low current peripheral drivers
- Replacement of general purpose transistors in digital applications
- Control of IC inputs.

### DESCRIPTION

PNP/PNP resistor-equipped transistors (see "Simplified outline, symbol and pinning" for package details).

### PRODUCT OVERVIEW

TYPE NUMBER	PACKAGE			NPN/PNP	NPN/NPN	
	IUMBER PHILIPS EIAJ MARKING CODE		COMPLEMENT	COMPLEMENT		
PEMB4	SOT666	_	B4	PEMD4	PEMH4	
PUMB4	SOT363	SC-88	B*4 <sup>(1)</sup>	PUMD4	PUMH4	

#### Note

1. \* = p: Made in Hong Kong.

\* = t: Made in Malaysia.

\* = W: Made in China.

#### SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PINNING		
	SIMPLIFIED OUTLINE AND STMBOL	PIN	DESCRIPTION	
PEMB4		1	emitter TR1	
PUMB4		2	base TR1	
		3	collector TR2	
		4	emitter TR2	
		5	base TR2	
		6	collector TR1	
	Top view MAM452			

## QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V <sub>CEO</sub>	collector-emitter voltage	-	-50	V
I <sub>O</sub>	output current (DC)	-	-100	mA
TR1	PNP	-	-	-
TR2	PNP	-	-	_
R1	bias resistor	10	-	kΩ
R2	bias resistor	open	_	-

### Product data sheet

## PEMB4; PUMB4

ORDERING INFORMATION

TYPE NUMBER	PACKAGE			
	NAME	DESCRIPTION	VERSION	
PEMB4	_	<ul> <li>plastic surface mounted package; 6 leads</li> </ul>		
PUMB4	-	<ul> <li>plastic surface mounted package; 6 leads</li> </ul>		

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per transi	stor	·			
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	-5	V
I <sub>O</sub>	output current (DC)		-	-100	mA
I <sub>CM</sub>	peak collector current		-	-100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	SOT363	note 1	-	200	mW
	SOT666	notes 1 and 2	_	200	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C
Per device	9				
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	SOT363	note 1	_	300	mW
	SOT666	notes 1 and 2	_	300	mW

### Notes

1. Device mounted on an FR4 printed-circuit board, single-sided copper, standard footprint.

2. Reflow soldering is the only recommended soldering method.

## PEMB4; PUMB4

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
Per transist	tor			
R <sub>th j-a</sub>	thermal resistance from junction to ambient	$T_{amb} \le 25 \ ^{\circ}C$		
	SOT363	note 1	625	K/W
	SOT666	notes 1 and 2	625	K/W
Per device				
R <sub>th j-a</sub>	thermal resistance from junction to ambient	$T_{amb} \le 25 \ ^{\circ}C$		
	SOT363	note 1	416	K/W
	SOT666	note 1	416	K/W

#### Notes

1. Device mounted on an FR4 printed-circuit board, single-sided copper, standard footprint.

2. Reflow soldering is the only recommended soldering method.

### CHARACTERISTICS

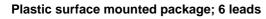
 $T_{amb} = 25 \ ^{\circ}C$  unless otherwise specified.

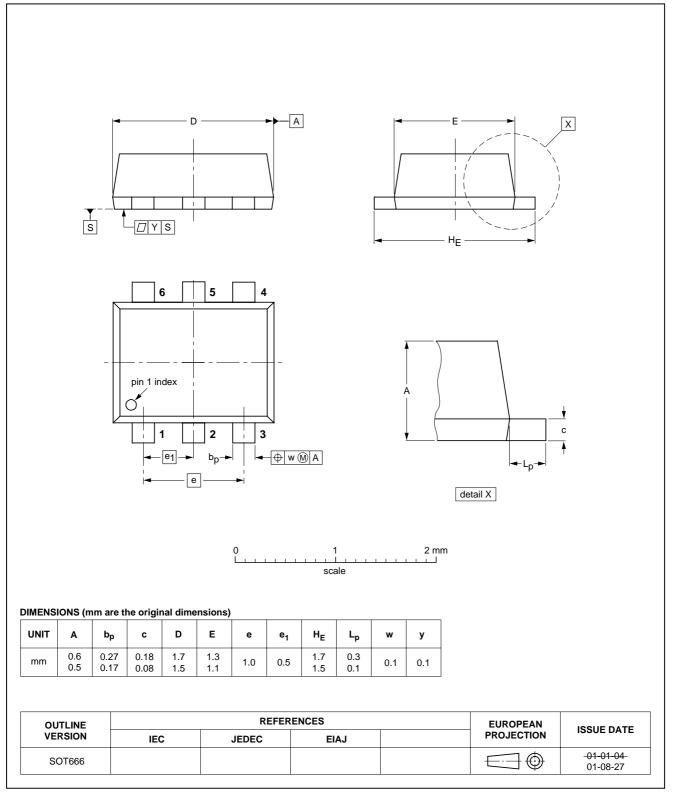
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = -50 \text{ V}; \text{ I}_{E} = 0$	-	_	-100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE} = -30 \text{ V}; I_B = 0$	-	-	-1	μA
		$V_{CE} = -30 \text{ V}; I_B = 0; T_j = 150 \text{ °C}$	-	-	-50	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0$	-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V}; I_C = -1 \text{ mA}$	200	_	_	
V <sub>CEsat</sub>	saturation voltage	$I_{\rm C} = -10$ mA; $I_{\rm B} = -0.5$ mA	-	-	-150	mV
R1	input resistor		7	10	13	kΩ
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0; V_{CB} = -10 V;$ f = 1 MHz	-	_	3	pF

**SOT666** 

# PNP/PNP resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = open

### PACKAGE OUTLINES





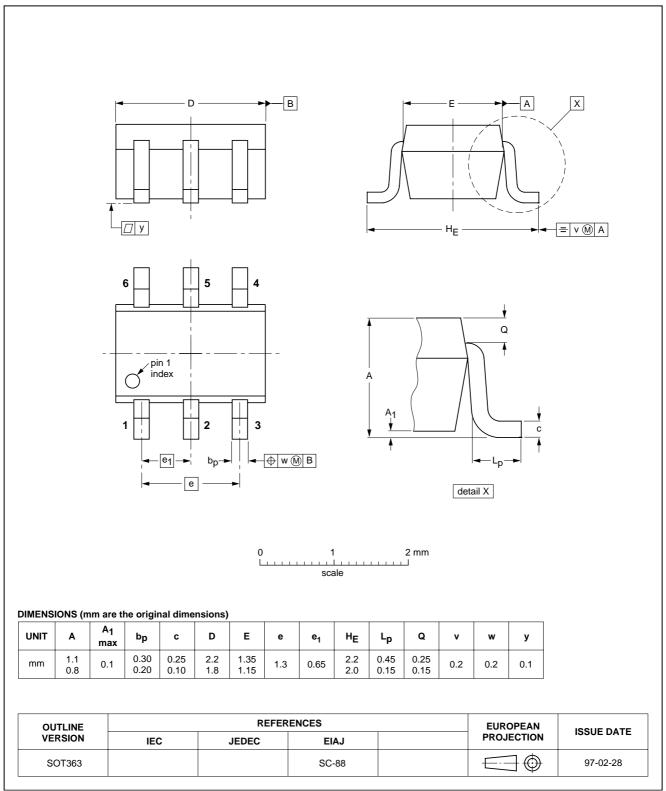
## PEMB4; PUMB4

**SOT363** 

# PNP/PNP resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = open

# PEMB4; PUMB4

### Plastic surface mounted package; 6 leads



## PEMB4; PUMB4

#### DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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# **NXP Semiconductors**

#### **Customer notification**

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#### **Contact information**

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